

# 4V Drive Nch + Nch MOSFET

## MP6K11

### ● Structure

Silicon N-channel MOSFET

### ● Features

- 1) Low on-resistance.
- 2) High power package(MPT6).
- 3) Low voltage drive(4V drive).

### ● Application

Switching

### ● Packaging specifications

Type	Package	Taping
	Code	TCR
	Basic ordering unit (pieces)	1000
MP6K11		○

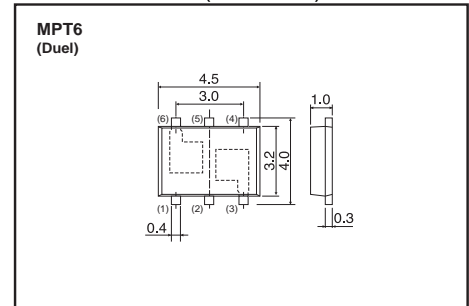
### ● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limits	Unit
Drain-source voltage	$V_{DSS}$	30	V
Gate-source voltage	$V_{GSS}$	±20	V
Drain current	Continuous	$I_D$	±3.5 A
	Pulsed	$I_{DP}^{*1}$	±12 A
Source current (Body Diode)	Continuous	$I_s$	1.6 A
	Pulsed	$I_{sp}^{*1}$	12 A
Power dissipation	$P_D^{*2}$	2.0	W / TOTAL
		1.4	W / ELEMENT
Channel temperature	Tch	150	°C
Range of storage temperature	Tstg	-55 to +150	°C

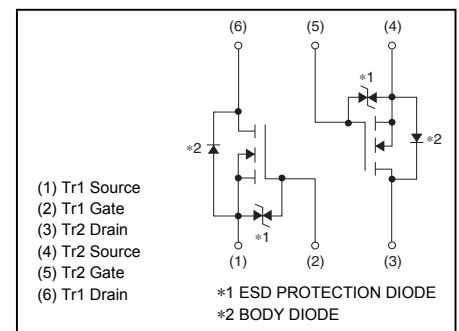
\*1  $P_w \leq 10\mu s$ , Duty cycle  $\leq 1\%$

\*2 Mounted on a ceramic board.

### ● Dimensions (Unit : mm)



### ● Inner circuit



● **Electrical characteristics** (Ta = 25°C)

<It is the same ratings for Tr1 and Tr2.>

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	$I_{GSS}$	–	–	±10	μA	$V_{GS}=\pm 20V, V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	30	–	–	V	$I_D=1mA, V_{GS}=0V$
Zero gate voltage drain current	$I_{DSS}$	–	–	1	μA	$V_{DS}=30V, V_{GS}=0V$
Gate threshold voltage	$V_{GS(th)}$	1.0	–	2.5	V	$V_{DS}=10V, I_D=1mA$
Static drain-source on-state resistance	$R_{DS(on)}^*$	–	70	98	mΩ	$I_D=3.5A, V_{GS}=10V$
		–	90	126		$I_D=3.5A, V_{GS}=4.5V$
		–	110	140		$I_D=3.5A, V_{GS}=4.0V$
Forward transfer admittance	$ Y_{fs} ^*$	1.5	–	–	S	$I_D=3.5A, V_{DS}=10V$
Input capacitance	$C_{iss}$	–	85	–	pF	$V_{DS}=10V$
Output capacitance	$C_{oss}$	–	40	–	pF	$V_{GS}=0V$
Reverse transfer capacitance	$C_{rss}$	–	20	–	pF	$f=1MHz$
Turnon delay time	$t_{d(on)}^*$	–	4	–	ns	$I_D=1.75A, V_{DD}=15V$
Rise time	$t_r^*$	–	8	–	ns	$V_{GS}=10V$
Turnoff delay time	$t_{d(off)}^*$	–	18	–	ns	$R_L=6.0\Omega$
Fall time	$t_f^*$	–	3	–	ns	$R_G=10\Omega$
Total gate charge	$Q_g^*$	–	1.9	–	nC	$I_D=3.5A, V_{DD}=15V$
Gate-source charge	$Q_{gs}^*$	–	0.8	–	nC	$V_{GS}=5V$
Gate-drain charge	$Q_{gd}^*$	–	0.4	–	nC	

\*Pulsed

● **Body diode characteristics** (Source-Drain) (Ta = 25°C)

<It is the same ratings for Tr1 and Tr2.>

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward Voltage	$V_{SD}^*$	–	–	1.2	V	$I_S=3.5A, V_{GS}=0V$

\*Pulsed

●Electrical characteristic curves (Ta=25°C)

Fig.1 Typical Output Characteristics( I )

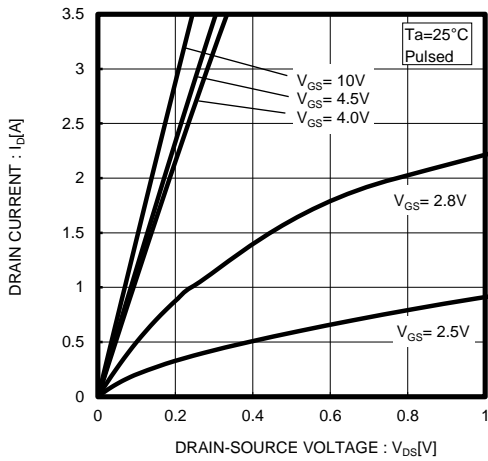


Fig.2 Typical Output Characteristics(II)

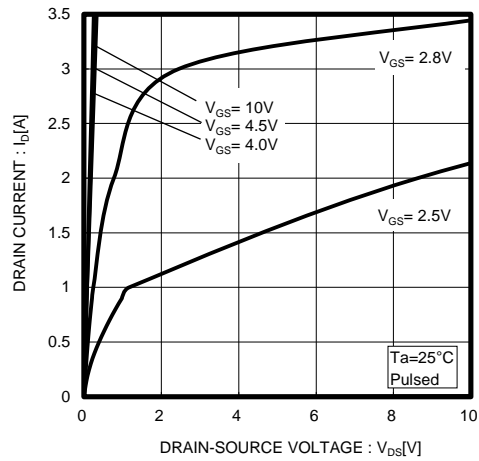


Fig.3 Typical Transfer Characteristics

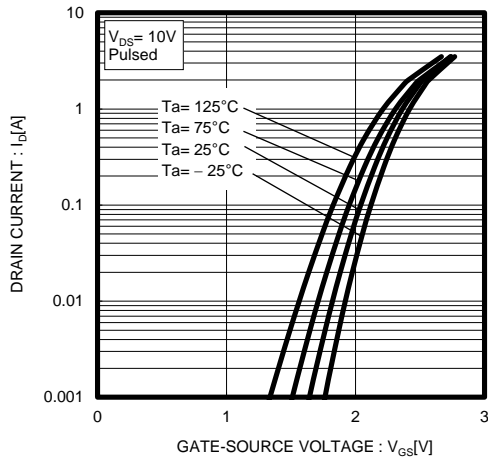


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current( I )

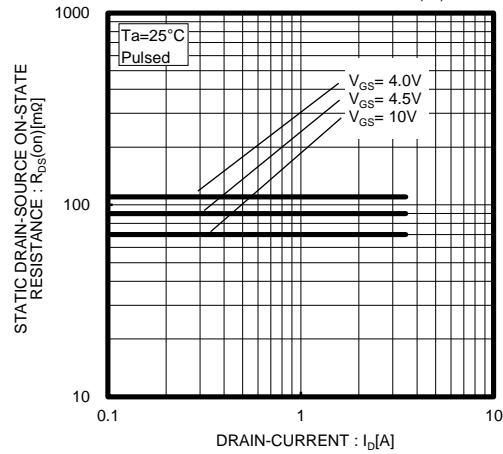


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current( II )

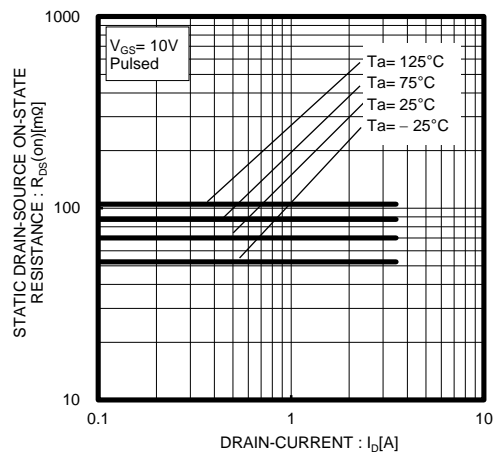


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(III)

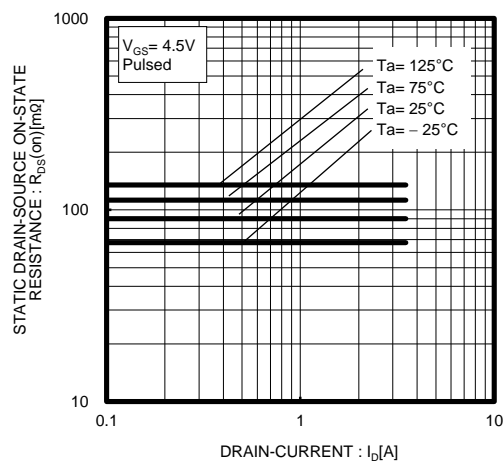


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current(I<sub>D</sub>)

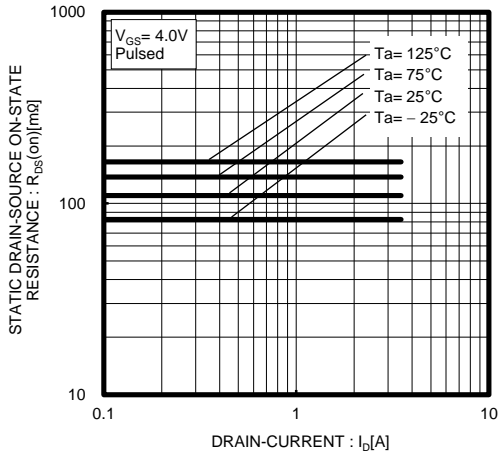


Fig.8 Forward Transfer Admittance vs. Drain Current

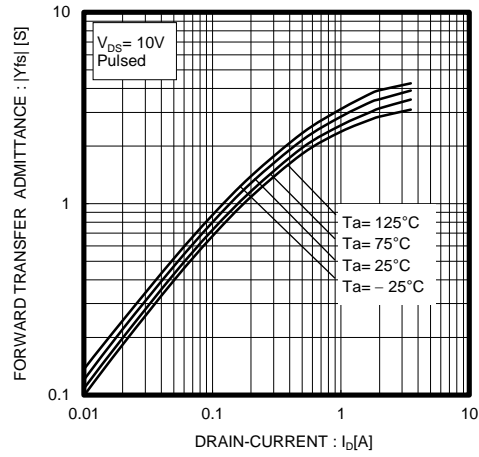


Fig.9 Reverse Drain Current vs. Source-Drain Voltage

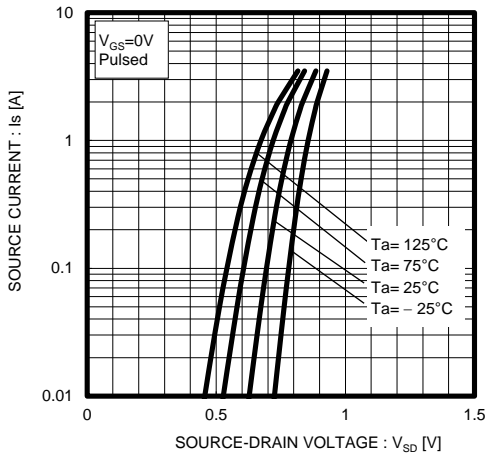


Fig.10 Static Drain-Source On-State Resistance vs. Gate Source Voltage

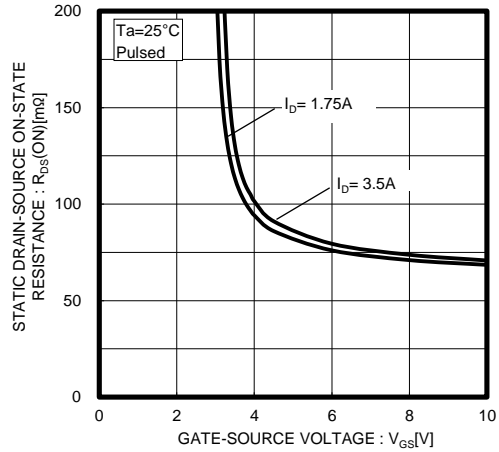


Fig.11 Switching Characteristics

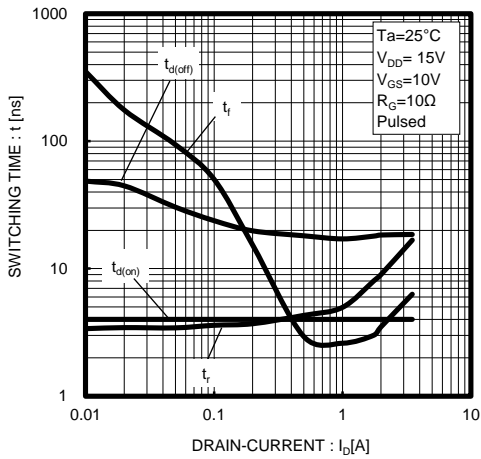


Fig.12 Dynamic Input Characteristics

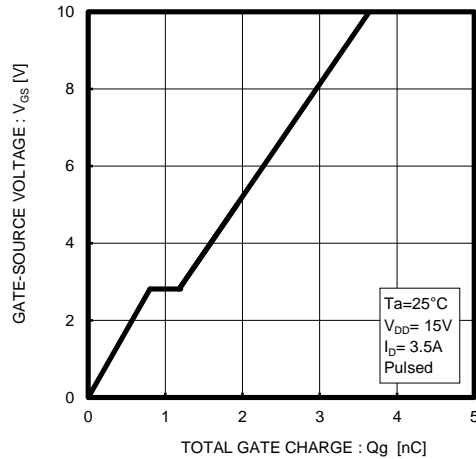


Fig.13 Typical Capacitance vs. Drain-Source Voltage

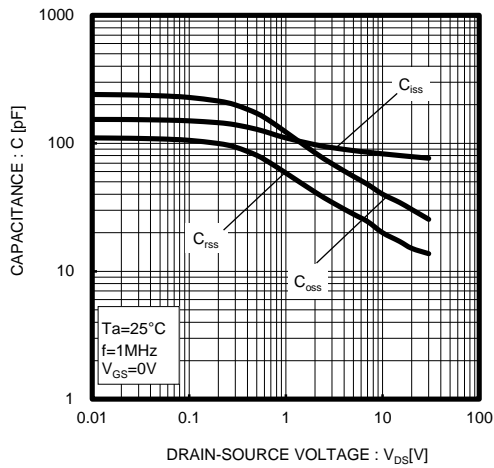


Fig.14 Maximum Safe Operating Area

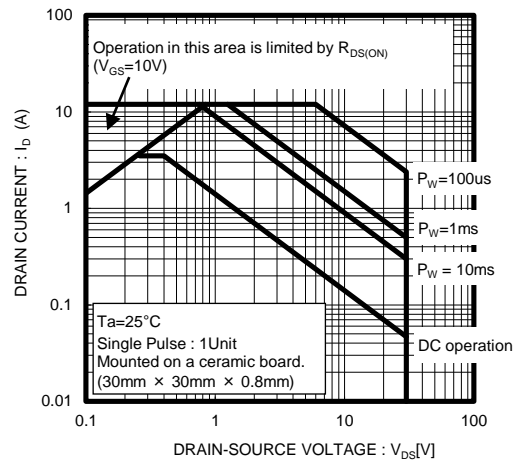
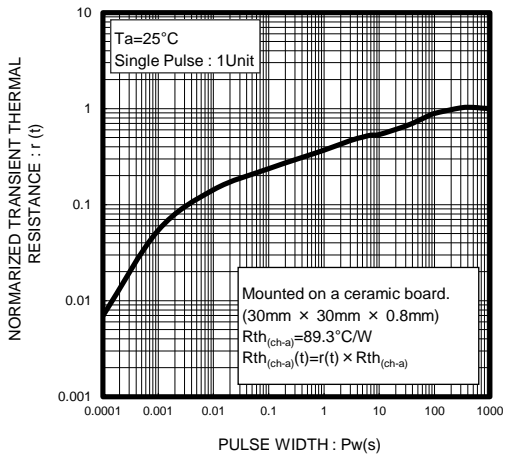


Fig.15 Normalized Transient Thermal Resistance vs. Pulse Width



● Measurement circuits

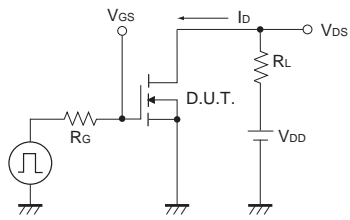


Fig.1-1 Switching Time Measurement Circuit

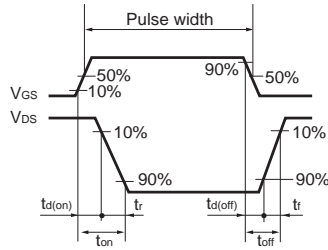


Fig.1-2 Switching Waveforms

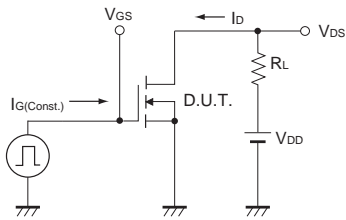


Fig.2-1 Gate Charge Measurement Circuit

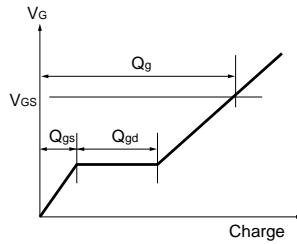


Fig.2-2 Gate Charge Waveform

● Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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